

US-Lasers: 780nm-5mW - Infrared Laser Diode and Infrared Diode Laser Module

Links to Laser Diode & Laser Module

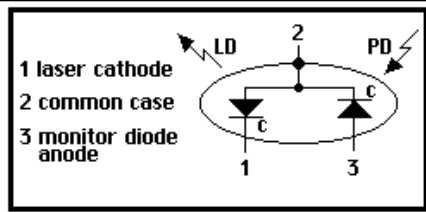
Configurations and Specifications >>>>>>>>>

[Laser Diode](#)
[Laser Diode Module](#)
[Micro Laser Module](#)
[Variable Output Laser Diode Module](#)
[N780-5](#)
[NM780-5](#)
[MM780-5](#)

Barrel Specs:	Weight & Wire Lengths:	Lens Housing Specs:
2 Pieces 12 - 56 Thread Size - Dia: 6.4mm - Length: 17mm	- Module with 6" wire leads - 49 grain wt. - Module without 6" wire leads - 42 grain wt - Module with spring leads - 42 1/2 grain wt. - Spring 2.4mm dia. 4mm long (trimmable)	12 - 56 Thread Size 3.0mm Aperture 4.0mm Plastic Lens

INFRARED DIODE LASER DATA SHEET

ABSOLUTE MAXIMUM RATINGS - (Tc=25 °C)

TECHNICAL DATA for LASER DIODE • Index Guided MQW Structure • Wavelength: 780nm (Typ.) • Optical Power: 5mW CW • Threshold Current: 25mA (Typ.) • Standard Package: 5.6mm		 Pin Out Diagram - Style A
Infrared light output	780nm	
Optical power output	5mW CW	
Package Type	5.6mm	
Built-in photo diode for monitoring laser output		

Pin Out Diagram - Style A

Items	Symbols	Values	Unit
Optical output power	Po	5	mW
Laser diode reverse voltage	VLDR	2	V
Photo diode reverse voltage	VPDR	30	V
Operating temperature	Topr	-10 ~ +40	°C
Storage temperature	Tstg	-40 ~ +85	°C

OPTICAL and ELECTRICAL CHARACTERISTICS - (Tc=25 °C)

Items	Symbols	Min.	Typ.	Max.	Unit	Test Condition
Optical output power	Po	-	5	-	mW	-
Threshold current	Ith	15	25	40	mA	-
Operating current	Iop	25	35	50	mA	Po=5mW
Operating voltage	Vop	1.9	2.1	2.5	V	Po=5mW
Lasing wavelength	λ D	770	780	790	nm	Po=5mW
Beam divergence	θ F	8	11	15	deg	Po=5mW
Beam divergence	θ z	20	35	45	deg	Po=5mW
Slope Efficiency (mW/mA)	η	0.1	0.3	0.6	-	-
Monitor current	Im	100	200	600	μ A	Po=5mW, Vr=5V
Astigmatism	As	-	11	-	μ m	Po=5mW
MTTF			3000-5,000 hrs.			Po=5mW, NA=0.4
Emitter Size		1 x 4 Microns				
Emitter Distance to Cap Lens		0.3mm				
Structure		Index Guided				